

Vishay Semiconductors

Small Signal Schottky Diode

Features

- For general purpose applications
- This diode features low turn-on voltage
- The devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition





ROHS COMPLIANT HALOGEN FREE



Applications

Applications where a very low forward voltage is required

Mechanical Data

Case: MiniMELF SOD-80
Weight: approx. 31 mg
Cathode band color: black
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/2.5K per 7" reel (8 mm tape), 12.5K/box

Parts Table

Part	Ordering code	Type Marking	Remarks
BAS85-M	BAS85-M-18 or BAS85-M-08	-	Tape and reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

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Parameter	Test condition	Symbol	Value	Unit
Continuous reverse voltage		V _R	30	V
Forward continuous current		I _F	200 ¹⁾	mA
Peak forward current		I _{FM}	300 ¹⁾	mA
Surge forward current	t _p < 1 s	I _{FSM}	600 ¹⁾	mA
Power dissipation	T _{amb} = 65 °C	P _{tot}	200 ¹⁾	mW

¹⁾ Valid provided that electrodes are kept at ambient temperature.

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		R _{thJA}	430 ¹⁾	K/W
Junction temperature		T _j	125	°C
Storage temperature range		T _{stg}	- 55 to +150	°C

¹⁾ Valid provided that electrodes are kept at ambient temperature.

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Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Reverse breakdown voltage	I _R = 10 μA (pulsed)	$V_{(BR)}$	30			V
Leakage current	V _R = 25 V	I _R		0.2	2	μΑ
Forward voltage	Pulse test $t_p < 300 \mu s$, $I_F = 0.1 \text{ mA}$	V_{F}			240	mV
	Pulse test $t_p < 300 \mu s$, $I_F = 1 mA$	V _F			320	mV
	Pulse test $t_p < 300 \mu s$, $I_F = 10 \text{ mA}$	V _F			400	mV
	Pulse test $t_p < 300 \mu s$, $I_F = 30 \text{ mA}$	V _F		500		mV
	Pulse test $t_p < 300 \mu s$, $I_F = 100 \text{ mA}$	V _F			800	mV
Diode capacitance	V _R = 1 V, f = 1 MHz	C _D			10	pF
Reverse recovery time	$I_F = 10 \text{ mA}, I_R = 10 \text{ mA},$ $I_{rr} = 1 \text{ mA},$	t _{rr}			5	ns

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

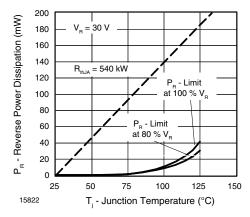


Figure 1. Max. Reverse Power Dissipation vs. Junction Temperature

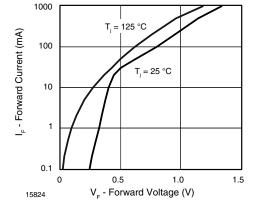


Figure 3. Forward Current vs. Forward Voltage

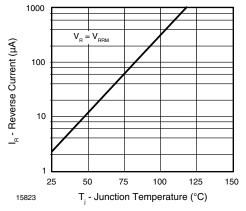


Figure 2. Reverse Current vs. Junction Temperature

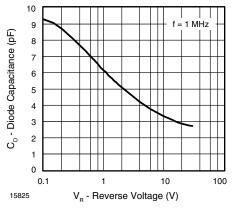


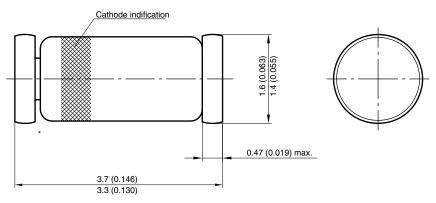
Figure 4. Diode Capacitance vs. Reverse Voltage

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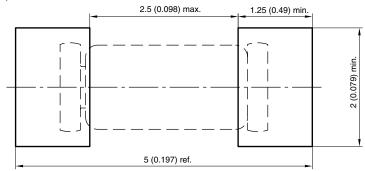
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Package Dimensions in millimeters (inches): MiniMELF SOD-80



^{*} The gap between plug and glass can be either on cathode or anode side





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